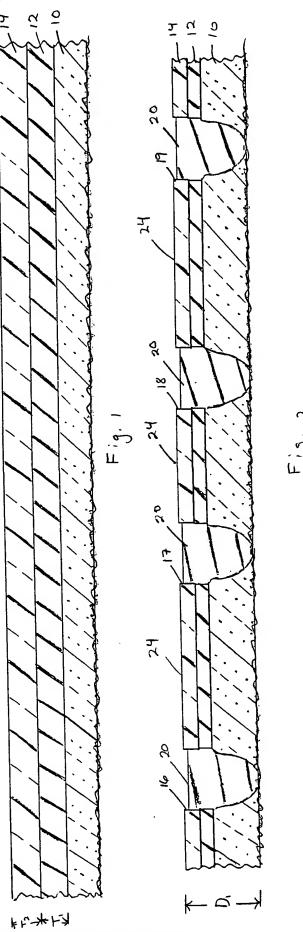
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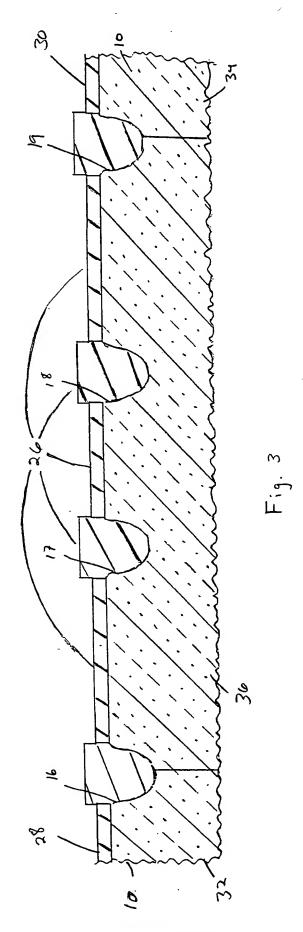
Matter No.: 10559-587001

Applicant(s): Applicant(s): Emiconductor and High-K GATE
DIELECTRIC METAL OXIDE SEMICONDUCTOR FIELD
EFFECT TRANSISTORS



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Matter No.: 10559-587001
Applicant Seen-Yih Jin et al.
NON-SIL SEMICONDUCTOR AND HIGH-K GATE
DIELECTA: METAL OXIDE SEMICONDUCTOR FIELD
EFFECT TRANSISTORS

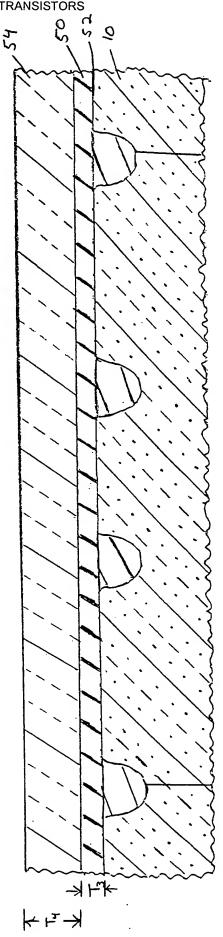


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Matter No.: 10559-587001

Applicant(s): Been-Yih Jin et al.

NEW SILICON SEMICONDUCTOR AND HIGH-K
DISSECTRIC METAL OXIDE SEMICONDUCTOR FREEFFECT TRANSISTORS



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NON-SILIC METAL OXIDE SEMICONDUCTOR FIELD
EFFECT TRANSISTORS

